



ISL6612BECBZ-T Information

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For Reference Only

Part Number ISL6612BECBZ-T

Manufacturer Renesas Electronics America

Category Integrated Circuits (ICs)
PMIC - Gate Drivers

DescriptionIC MOSFET DRVR SYNC BUCK 8EPSOIC**Package**8-SOIC (0.154", 3.90mm Width) Exposed Pad

For the pricing/inventory/lead time, please contact

us

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ISL6612BECBZ-T Specifications

Manufacturer Part NumberISL6612BECBZ-TManufacturerRenesas Electronics AmericaCategoryIntegrated Circuits (ICs)Package8-SOIC (0.154", 3.90mm Width) Exposed PadSeries-Driven ConfigurationHalf-BridgeChannel TypeSynchronousNumber of Drivers2Gate TypeN-Channel MOSFETVoltage - Supply7 V ~ 13.2 VLogic Voltage - VIL, VIH-Current - Peak Output (Source, Sink)1.25A, 2AInput TypeNon-InvertingHigh Side Voltage - Max (Bootstrap)36VRise / Fall Time (Typ)26ns, 18nsOperating Temperature0°C ~ 125°C (TJ)Mounting TypeSurface MountPackage / Case8-SOIC (0.154", 3.90mm Width) Exposed PadSupplier Device Package8-SOIC-EP		
Category Integrated Circuits (ICs) PMIC - Gate Drivers Package 8-SOIC (0.154", 3.90mm Width) Exposed Pad Series - Driven Configuration Half-Bridge Channel Type Synchronous Number of Drivers 2 Gate Type N-Channel MOSFET Voltage - Supply 7 V ~ 13.2 V Logic Voltage - VIL, VIH - Current - Peak Output (Source, Sink) Input Type Non-Inverting High Side Voltage - Max (Bootstrap) 36V Rise / Fall Time (Typ) Operating Temperature 0°C ~ 125°C (TJ) Mounting Type Package / Case 8-SOIC (0.154", 3.90mm Width) Exposed Pad Supplier Device Package	Manufacturer Part Number	ISL6612BECBZ-T
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Number of Drivers Gate Type N-Channel MOSFET Voltage - Supply 7 V ~ 13.2 V Logic Voltage - VIL, VIH - Current - Peak Output (Source, Sink) Input Type Non-Inverting High Side Voltage - Max (Bootstrap) Rise / Fall Time (Typ) Operating Temperature 0°C ~ 125°C (TJ) Mounting Type Surface Mount Package / Case 8-SOIC (0.154", 3.90mm Width) Exposed Pad Supplier Device Package	Driven Configuration	Half-Bridge
Gate Type N-Channel MOSFET 7 V ~ 13.2 V Logic Voltage - VIL, VIH - Current - Peak Output (Source, Sink) Input Type Non-Inverting High Side Voltage - Max (Bootstrap) Rise / Fall Time (Typ) Operating Temperature O°C ~ 125°C (TJ) Mounting Type Surface Mount Package / Case 8-SOIC (0.154", 3.90mm Width) Exposed Pad Supplier Device Package	Channel Type	Synchronous
Voltage - Supply Logic Voltage - VIL, VIH - Current - Peak Output (Source, Sink) Input Type Non-Inverting High Side Voltage - Max (Bootstrap) Rise / Fall Time (Typ) Operating Temperature O°C ~ 125°C (TJ) Mounting Type Surface Mount Package / Case 8-SOIC (0.154", 3.90mm Width) Exposed Pad Supplier Device Package	Number of Drivers	2
Logic Voltage - VIL, VIH Current - Peak Output (Source, Sink) Input Type Non-Inverting High Side Voltage - Max (Bootstrap) Rise / Fall Time (Typ) Operating Temperature O°C ~ 125°C (TJ) Mounting Type Surface Mount Package / Case 8-SOIC (0.154", 3.90mm Width) Exposed Pad Supplier Device Package	Gate Type	N-Channel MOSFET
Current - Peak Output (Source, Sink) Input Type Non-Inverting High Side Voltage - Max (Bootstrap) Rise / Fall Time (Typ) Operating Temperature O°C ~ 125°C (TJ) Mounting Type Surface Mount Package / Case 8-SOIC (0.154", 3.90mm Width) Exposed Pad Supplier Device Package	Voltage - Supply	7 V ~ 13.2 V
Input Type Non-Inverting High Side Voltage - Max (Bootstrap) 36V Rise / Fall Time (Typ) 26ns, 18ns Operating Temperature 0°C ~ 125°C (TJ) Mounting Type Surface Mount Package / Case 8-SOIC (0.154", 3.90mm Width) Exposed Pad Supplier Device Package 8-SOIC-EP	Logic Voltage - VIL, VIH	-
High Side Voltage - Max (Bootstrap) Rise / Fall Time (Typ) 26ns, 18ns Operating Temperature 0°C ~ 125°C (TJ) Mounting Type Surface Mount Package / Case 8-SOIC (0.154", 3.90mm Width) Exposed Pad Supplier Device Package 8-SOIC-EP	Current - Peak Output (Source, Sink)	1.25A, 2A
Rise / Fall Time (Typ) 26ns, 18ns Operating Temperature 0°C ~ 125°C (TJ) Mounting Type Surface Mount Package / Case 8-SOIC (0.154", 3.90mm Width) Exposed Pad Supplier Device Package 8-SOIC-EP	Input Type	Non-Inverting
Operating Temperature0°C ~ 125°C (TJ)Mounting TypeSurface MountPackage / Case8-SOIC (0.154", 3.90mm Width) Exposed PadSupplier Device Package8-SOIC-EP	High Side Voltage - Max (Bootstrap)	36V
Mounting Type Surface Mount Package / Case 8-SOIC (0.154", 3.90mm Width) Exposed Pad Supplier Device Package 8-SOIC-EP	Rise / Fall Time (Typ)	26ns, 18ns
Package / Case 8-SOIC (0.154", 3.90mm Width) Exposed Pad Supplier Device Package 8-SOIC-EP	Operating Temperature	0°C ~ 125°C (TJ)
Supplier Device Package 8-SOIC-EP	Mounting Type	Surface Mount
	Package / Case	8-SOIC (0.154", 3.90mm Width) Exposed Pad
Report errors?	Supplier Device Package	8-SOIC-EP
		Report errors

ISL6612BECBZ-T Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

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